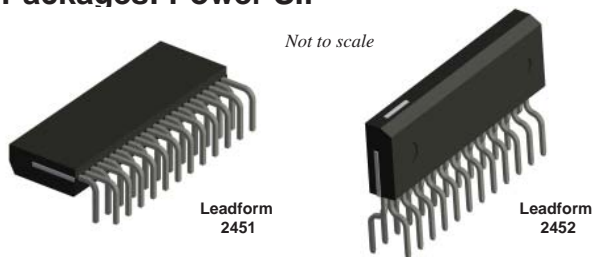


High Voltage 3-Phase Motor Driver

Features and Benefits

- Built-in pre-drive IC
- MOSFET power element
- Alleviate noise generation by adjusting an internal resistor
- CMOS compatible input (5 V)
- High-side gate driver using bootstrap circuit or floating power supply
- Built-in protection circuit for controlling power supply voltage drop (UVLO on VCC)
- Overcurrent protection (OCP), overcurrent limiting (OCL), and thermal shutdown (TSD)
- Output of fault signal during operation of protection circuit
- Output current 1.5 A
- Small SIP (SMA 24-pin)

Packages: Power SIP



Description

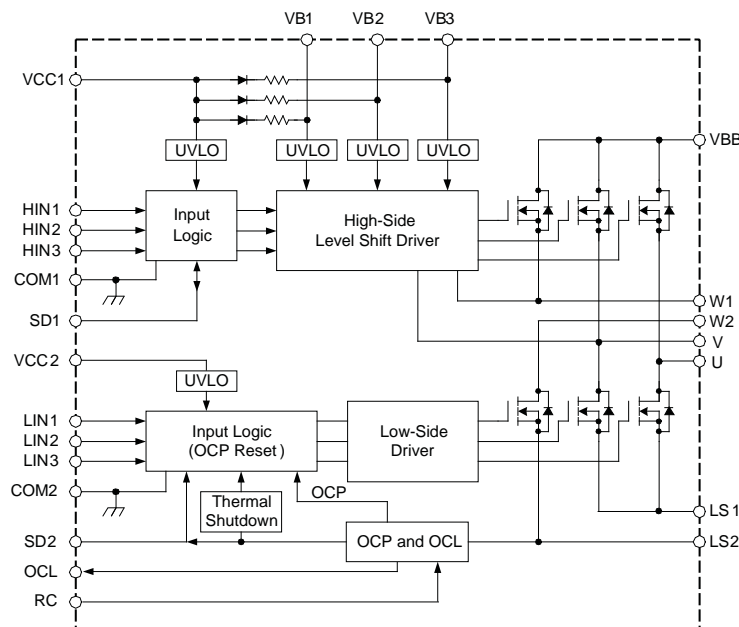
The SMA6862M inverter power module (IPM) device provides a robust, highly-integrated solution for optimally controlling 3-phase motor power inverter systems and variable speed control systems used in energy-conserving designs to drive motors of residential and commercial appliances. These ICs take 230 VAC input voltage, and 1.5 A (continuous) output current. They can withstand voltages of up to 500 V (MOSFET breakdown voltage).

The SMA6800M power package includes an IC with all of the necessary power elements (six MOSFETs), pre-driver ICs (two), and bootstrap diodes (three), needed to configure the main circuit of an inverter. This enables the main circuit of the inverter to be configured with fewer external components than traditional designs.

Applications include residential white goods (home applications) and commercial appliance motor control:

- Air conditioner fan
- Refrigerator compressor
- Dishwasher pump

Functional Block Diagram



- A. SD1, SD2 terminals are used for both input and output.
 B. SD1, SD2, and OCL terminals are open-collector output. RC terminal is open-drain output.
 C. Blanking Time (t_{blank}) is used in Overcurrent Limiting (OCL) and Overcurrent Protection (OCP).
 If the time exceeds the limit, the signal will be output (open-collector output turns on), and protection operation will start up.

Figure 1. Driver block diagram.

Selection Guide

Part Number	Packing	MOSFET Breakdown Voltage, $V_{DSS(min)}$ (V)	Output Current	
			Continuous, $I_O(max)$ (A)	Pulsed, $I_{OP}(max)$ (A)
SMA6862M	18 pieces per tube	500	1.5	3

Absolute Maximum Ratings, valid at $T_A = 25^\circ\text{C}$

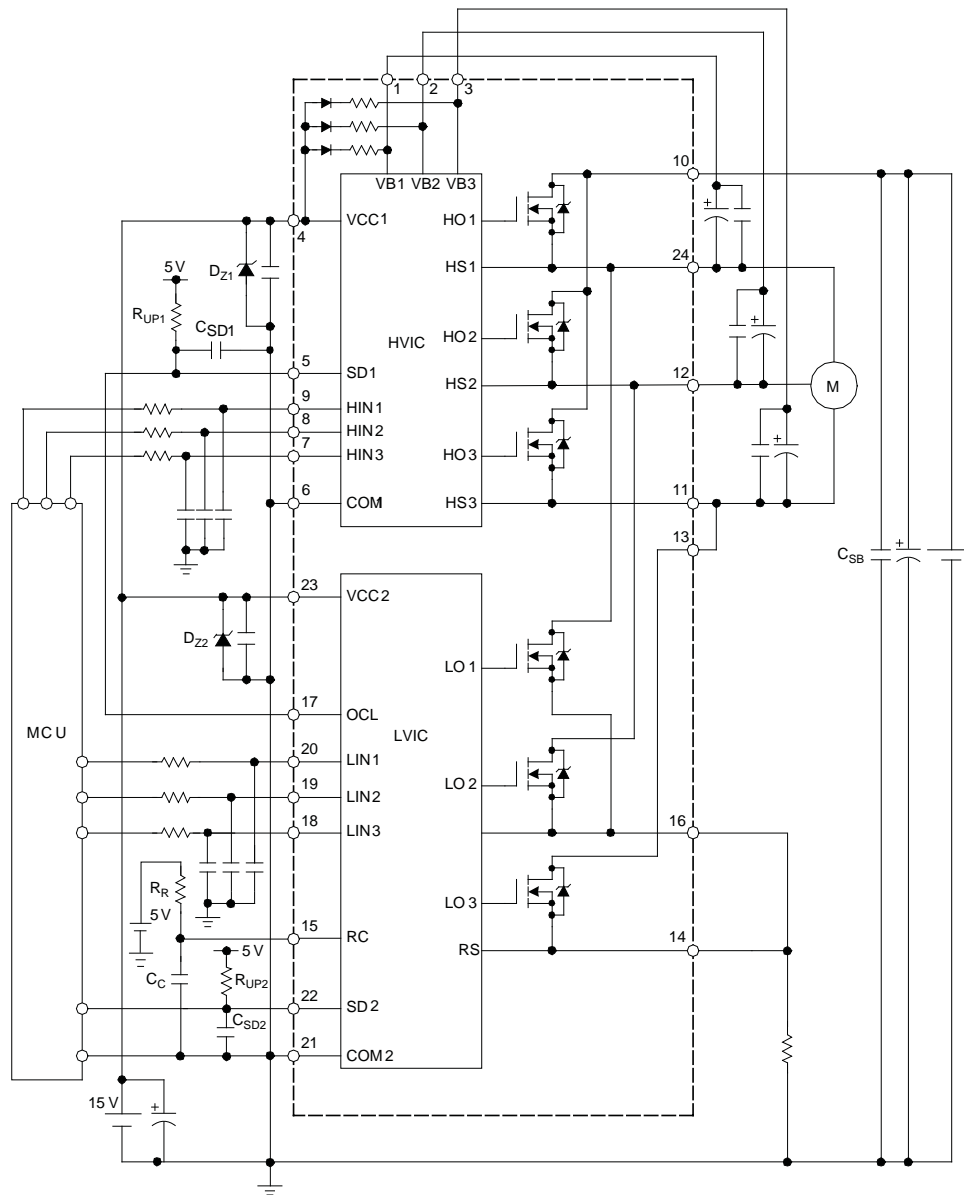
Characteristic	Symbol	Remarks	Rating	Unit
MOSFET Breakdown Voltage	V_{DSS}	$V_{CC} = 15\text{ V}$, $I_D = 100\ \mu\text{A}$, $V_{IN} = 0\text{ V}$	500	V
Logic Supply Voltage	V_{CC}	Between VCC and COM	20	V
Bootstrap Voltage	V_{BS}	Between VB and HS (U, V, and W phases)	20	V
Output Current, Continuous	I_O		1.5	A
Output Current, Pulsed	I_{OP}	$PW \leq 100\ \mu\text{s}$, duty cycle = 1%	3	A
Input Voltage	V_{IN}	HINx and LINx pins	-0.5 to 7	V
Pull-up Voltage for Shutdown Pins	V_{SDX}	SDx pins	7	V
Pull-up Voltage for Overcurrent Limiting Pin	V_{OCL}		7	V
Allowable Power Dissipation	P_D	$T_C = 25^\circ\text{C}$	28	W
Thermal Resistance (Junction to Case)	$R_{\theta JC}$	All elements operating	4.5	$^\circ\text{C/W}$
Thermal Resistance (Junction to Case)	$R_{\theta JA}$	All elements operating	31.25	$^\circ\text{C/W}$
Case Operating Temperature	T_{COP}		-20 to 100	$^\circ\text{C}$
Junction Temperature (MOSFET)	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-40 to 150	$^\circ\text{C}$

Recommended Operating Conditions

Characteristic	Symbol	Remarks	Min.	Typ.	Max.	Units
Main Supply Voltage	V_{BB}	Between VBB and LS	-	-	400	V
V_{BB} Snubber Capacitor	C_{SB}		0.01	-	0.1	μF
Logic Supply Voltage	V_{CC}	Between VCC and COM	13.5	15	16.5	V
Zener Voltage for VCCx Pins	V_Z	Between VCC and COM	18	-	20	V
Pull-up Voltage	V_{SDX}, V_{OCL}		4.5	5	5.5	V
Pull-up Resistor SDx Pins	R_{UPX}		3.3	-	10	$\text{k}\Omega$
Pull-up Resistor OCL Pin	$R_{OCL(up)}$		1	-	10	$\text{k}\Omega$
Pull-up Resistor RC Pin	R_R		33	-	390	$\text{k}\Omega$
Capacitor SDX and OCL Pins	C_{SDX}, C_{OCL}		1	-	10	nF
Capacitor RC Pin	C_C		1	-	4.7	nF
Dead Time	t_{dead}	$T_J = -20^\circ\text{C}$ to 150°C	1.5	-	-	μs
Minimum Input Pulse Width	$I_{INMIN(on)}$	$T_J = -20^\circ\text{C}$ to 150°C	0.5	-	-	μs
	$I_{INMIN(off)}$	$T_J = -20^\circ\text{C}$ to 150°C	0.5	-	-	μs
Switching Frequency	f_{PWM}		-	-	20	kHz
Junction Temperature	T_J		-	-	125	$^\circ\text{C}$

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature, T_A , of 25°C , unless otherwise stated.

Typical Application Diagram



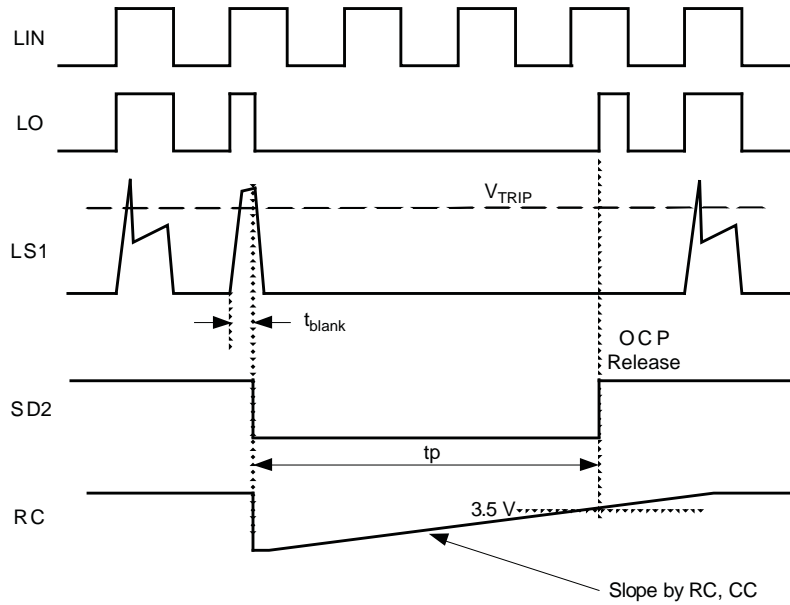
NOTE:

The external electrolytic capacitors should be placed as close to the IC as possible, in order to avoid malfunctions from external noise interference. Put a ceramic capacitor in parallel with the electrolytic capacitor if further reduction of noise susceptibility is necessary.

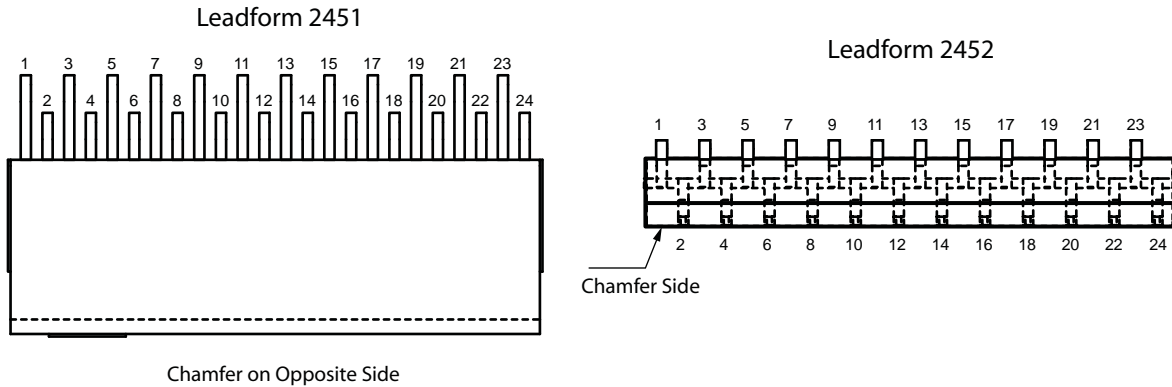
ELECTRICAL CHARACTERISTICS, valid at $T_A=25^\circ\text{C}$, unless otherwise noted

Characteristics	Symbol	Conditions	Min	Typ	Max	Units	
Logic Supply Current	I_{CC}	$V_{CC} = 15\text{ V}$, $T_C = -20^\circ\text{C}$ to 125°C	–	4.2	7	mA	
Bootstrap Supply Current	I_{BX}	$V_{BX} = 15\text{ V}$, $V_{HIN} = 5\text{ V}$, $T_C = -20^\circ\text{C}$ to 125°C	–	135	380	μA	
Input Voltage	V_{IH}	$V_{CC} = 15\text{ V}$	–	2.9	3.4	V	
	V_{IL}	$V_{CC} = 15\text{ V}$	1.6	2.1	–	V	
Input Voltage Hysteresis	V_{Ihys}	$V_{CC} = 15\text{ V}$	–	0.8	–	V	
Input Current	I_{IN}	$V_{IN} = 5\text{ V}$	–	230	500	μA	
Undervoltage Lock Out	V_{UVHL}	High side, between V_{Bx} and U, V, or W	9.0	10.0	11.0	V	
	V_{UVHH}		9.5	10.5	11.5	V	
	V_{UVHhys}	High side, hysteresis	–	0.5	–	V	
	V_{UVLL}	Low side, between V_{CC2} and COM2	10.0	11.0	12.0	V	
	V_{UVLH}		10.5	11.5	12.5	V	
	V_{UVLhys}	Low side, hysteresis	–	0.5	–	V	
SDx and OCL Output Voltage	$V_{SDX(on)}$, V_{OCL}	$V_{SDX} = V_{OCL} = 5\text{ V}$, $R_{UPX} = 3.3\text{ k}\Omega$	–	–	0.6	V	
Overtemperature Detection Threshold Temperature (Activation and Deactivation)	T_{DH}	$V_{CC} = 15\text{ V}$, high-side and low side	120	135	150	$^\circ\text{C}$	
	T_{DL}		100	115	130	$^\circ\text{C}$	
	T_{Dhys}		–	20	–	$^\circ\text{C}$	
Overcurrent Protection Trip Voltage	V_{TRIP}	$V_{CC} = 15\text{ V}$, $T_C = -20^\circ\text{C}$ to 100°C	0.9	1.0	1.1	V	
Overcurrent Limiting Reference Voltage	V_{LIM}	$V_{CC} = 15\text{ V}$, $T_C = -20^\circ\text{C}$ to 100°C	0.5035	0.53	0.5565	V	
Overcurrent Protection Hold Time	t_p	$V_{RC} = 5\text{ V}$, $R_R = 360\text{ k}\Omega$, $C_C = 0.0047\text{ }\mu\text{F}$	–	2.0	–	ms	
Blanking Time	t_{blank}	$V_{CC} = 15\text{ V}$	1.4	2.0	2.6	μs	
Bootstrap Diode Leakage Current	I_{LBD}	$V_R = 500\text{ V}$	–	–	10	μA	
Bootstrap Diode Forward Voltage	V_{FBD}	$I_F = 0.15\text{ A}$	–	1.1	1.3	V	
Bootstrap Diode Recovery Time	t_{trb}	$I_F / I_{RP} = 100\text{ mA} / 100\text{ mA}$	–	70	–	ns	
Bootstrap Diode Series Resistor	R_{BD}		168	210	252	Ω	
MOSFET Breakdown Voltage	V_{DSS}	$V_{CC} = 15\text{ V}$, $I_D = 100\text{ }\mu\text{A}$, $V_{IN} = 0\text{ V}$	500	–	–	V	
MOSFET Leakage Current	I_{DSS}	$V_{CC} = 15\text{ V}$, $V_{DS} = 500\text{ V}$, $V_{IN} = 0\text{ V}$	–	–	100	μA	
MOSFET On State Resistance	$R_{DS(on)}$	$V_{CC} = 15\text{ V}$, $I_D = 1.5\text{ A}$, $V_{IN} = 5\text{ V}$	–	3.6	4.0	Ω	
MOSFET Diode Forward Voltage	V_{SDF}	$V_{CC} = 15\text{ V}$, $I_{SD} = 1.5\text{ A}$, $V_{IN} = 0\text{ V}$	–	1.1	1.5	V	
Switching Time, High Side	$t_{dH(on)}$	$V_{BB} = 300\text{ V}$, $V_{CC} = 15\text{ V}$, $I_D = 1.5\text{ A}$, $0\text{ V} \leq V_{IN} \leq 5\text{ V}$	–	722	–	ns	
	t_{rH}		–	40	–	ns	
	t_{rrH}		–	110	–	ns	
	$t_{dH(off)}$		–	668	–	ns	
	t_{fH}		–	22	–	ns	
Switching Time, Low Side	$t_{dL(on)}$			–	596	–	ns
	t_{rL}			–	40	–	ns
	t_{rrL}			–	120	–	ns
	$t_{dL(off)}$			–	554	–	ns
	t_{fL}			–	22	–	ns

Low-Side Input/Output Timing Diagram



Pin-out Diagrams

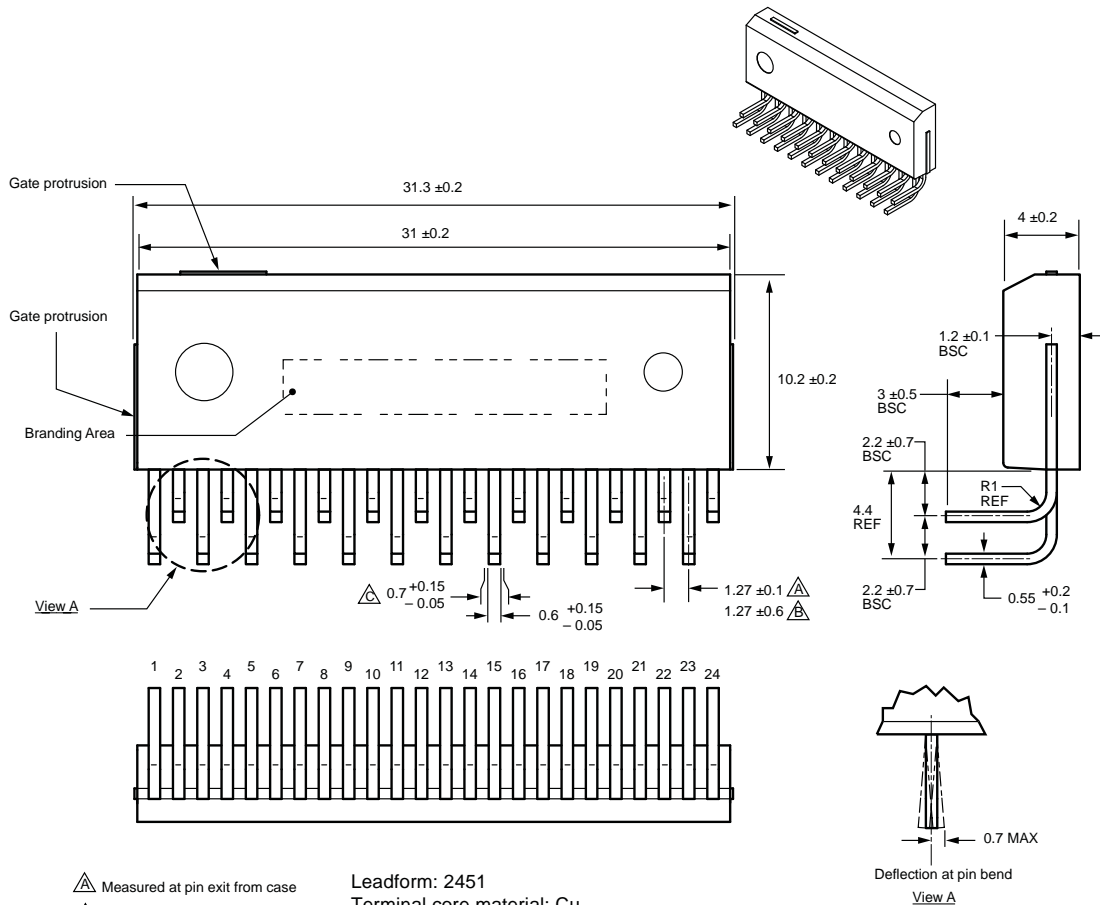


Terminal List Table

Number	Name	Function
1	VB1	High side bootstrap terminal (U phase)
2	VB2	High side bootstrap terminal (V phase)
3	VB3	High side bootstrap terminal (W phase)
4	VCC1	High side logic supply voltage
5	SD1	High side shutdown input and overtemperature fault signal output (open-collector output)
6	COM1	High side logic GND terminal
7	HIN3	High side input terminal (W phase)
8	HIN2	High side input terminal (V phase)
9	HIN1	High side input terminal (U phase)
10	VBB	Main supply voltage
11	W1	Output of W phase (connect to W2 externally)
12	V	Output of V phase
13	W2	Output of W phase (connect to W1 externally)
14	LS2	Low side emitter terminal (connect to LS1 externally)
15	RC	Overcurrent protection hold time adjustment input terminal and open-drain output
16	LS1	Low side emitter terminal (connect to LS2 externally)
17	OCL	Output for overcurrent limiting (open-collector output)
18	LIN3	Low side input terminal (W phase)
19	LIN2	Low side input terminal (V phase)
20	LIN1	Low side input terminal (U phase)
21	COM2	Low side GND terminal
22	SD2	Low side shutdown input and overtemperature and overcurrent fault signals output (open-collector output)
23	VCC2	Low side logic supply voltage
24	U	Output of U phase

Package Outline Drawing Leadform 2451

Dual rows, 24 alternating pins; pins bent 90° for horizontal case mounting; pin #1 in outer row



- △ Measured at pin exit from case
- △ Measured at pin tips
- △ Maximum dambar protrusion

Leadform: 2451
Terminal core material: Cu
Terminal plating: Ni and solder (Sn 97.5%, Ag 2.5%) plating
Case material: Epoxy resin

Dimensions in millimeters

Branding codes (exact appearance at manufacturer discretion):

1st line, lot: YMDDT
Where: Y is the last digit of the year of manufacture
M is the month (1 to 9, O, N, D)
DD is the date
T is the tracking letter

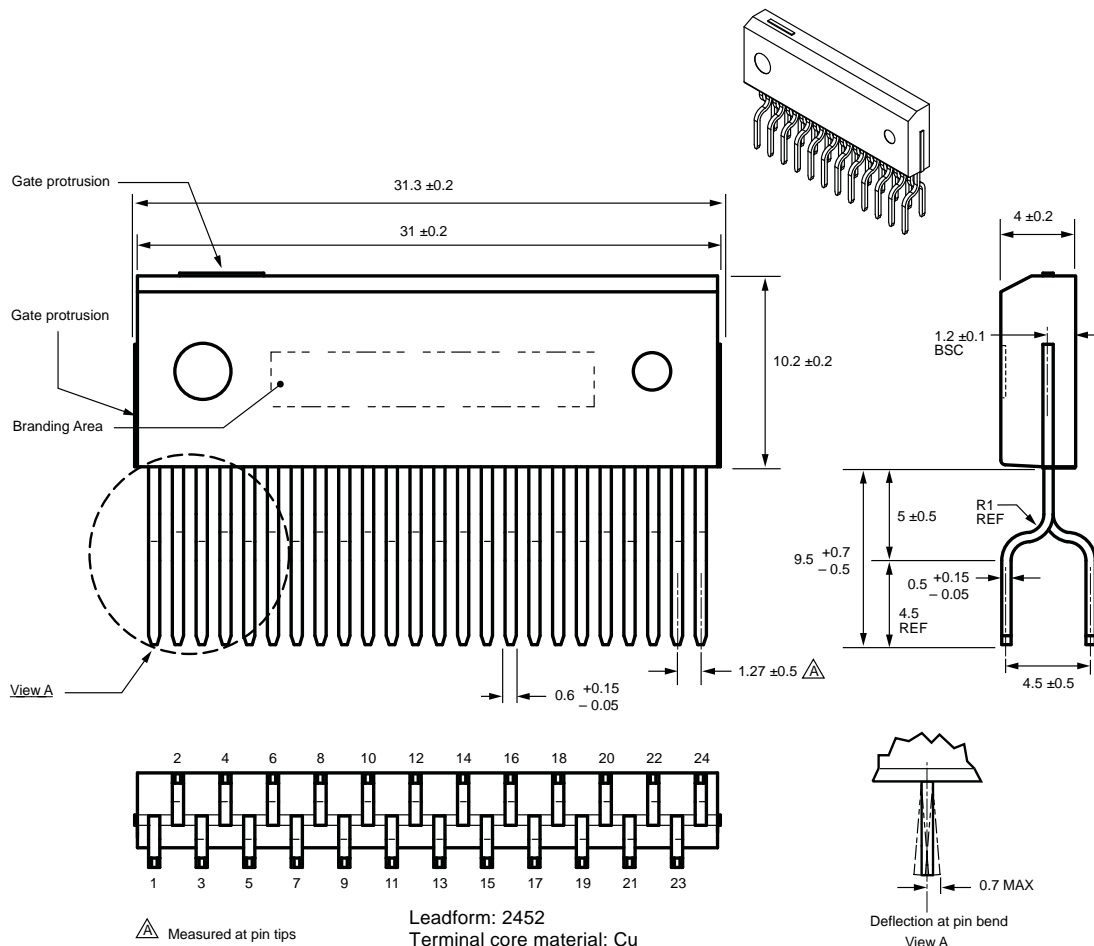
2nd line, type: SMA6862M



Leadframe plating Pb-free. Device composition complies with the RoHS directive.

Package Outline Drawing Leadform 2452

Dual rows, 24 alternating pins; vertical case mounting; pin #1 opposite chamfer side



\triangle Measured at pin tips

Leadform: 2452
Terminal core material: Cu
Terminal plating: Ni
Recommended attachment: Solder dip (Sn-Ag-Cu)

Dimensions in millimeters

Branding codes (exact appearance at manufacturer discretion):

1st line, lot: YMDDT

Where: Y is the last digit of the year of manufacture

M is the month (1 to 9, O, N, D)

DD is the date

T is the tracking letter

2nd line, type: SMA6862M

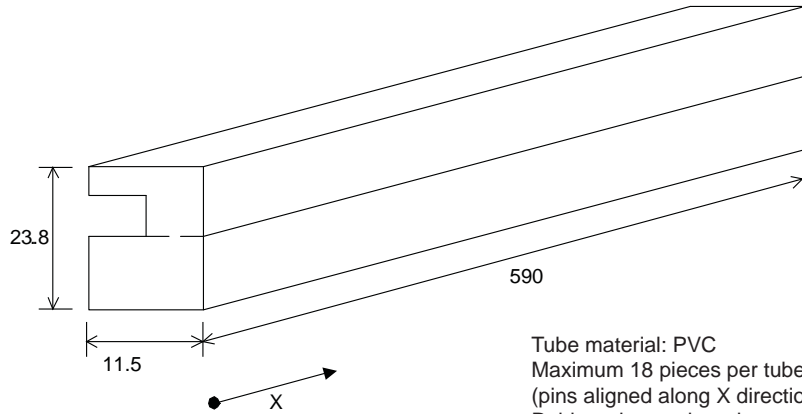


Leadframe plating Pb-free. Device composition complies with the RoHS directive.

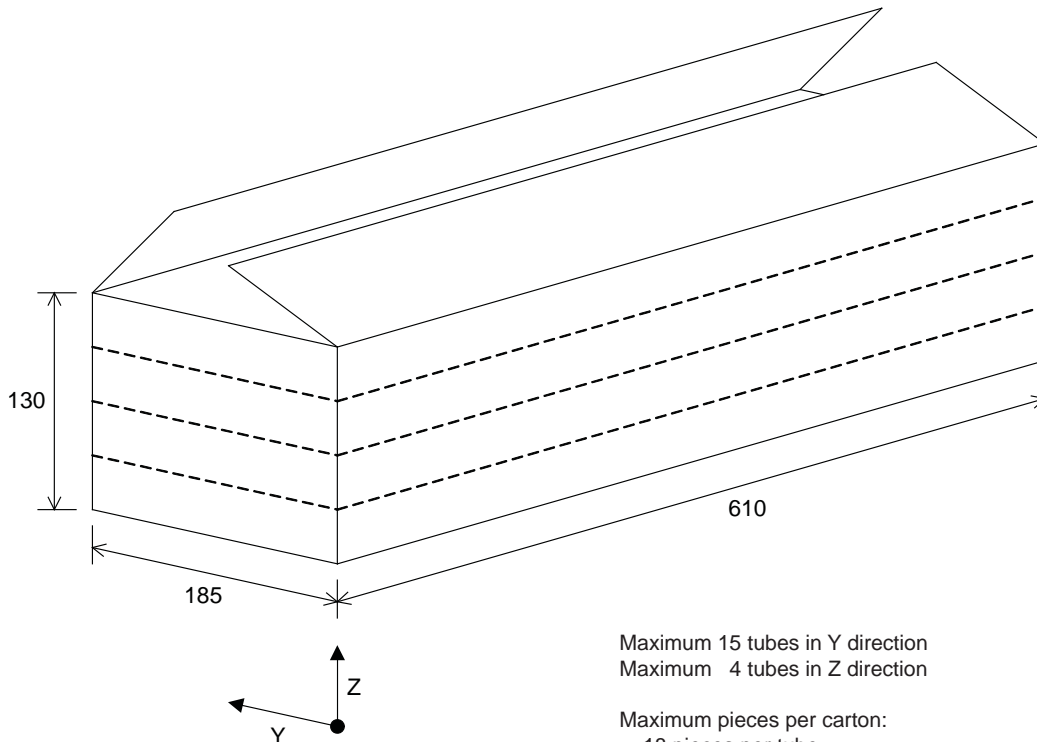
Packing Specification

Leadform 2451

Dimensions in millimeters



Tube material: PVC
Maximum 18 pieces per tube
(pins aligned along X direction)
Rubber plug each end



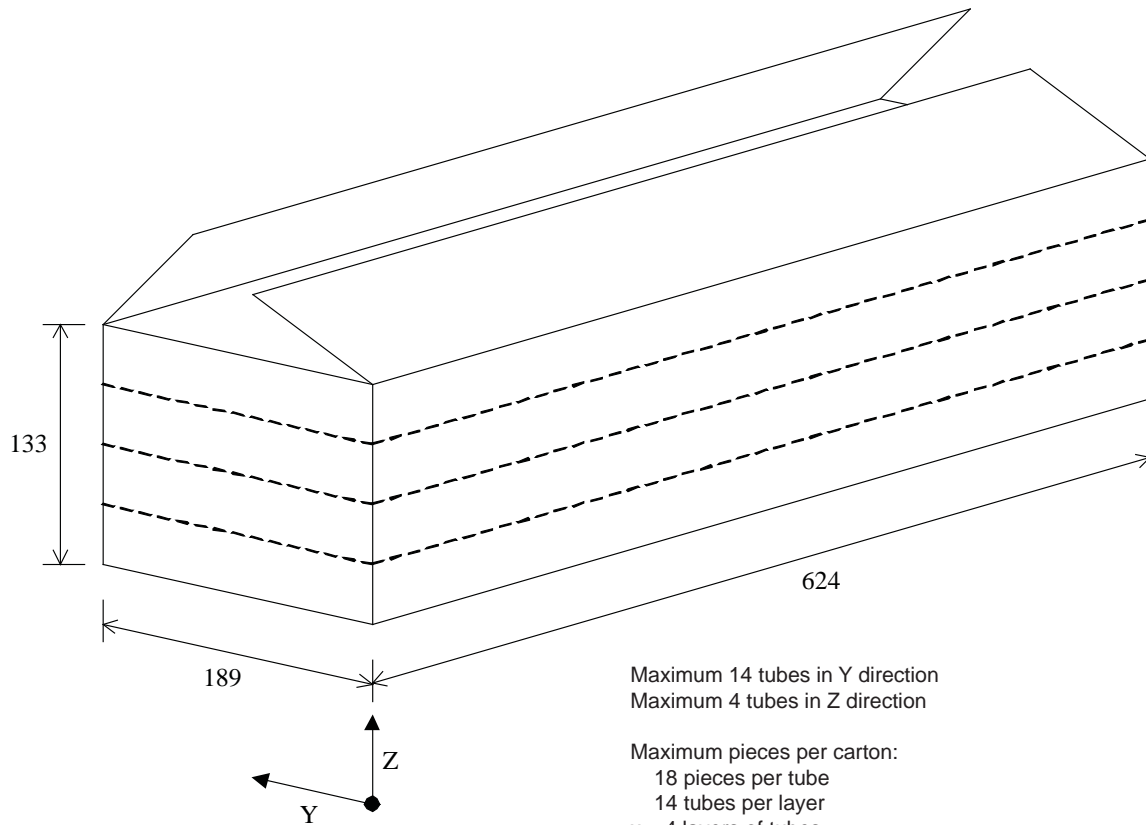
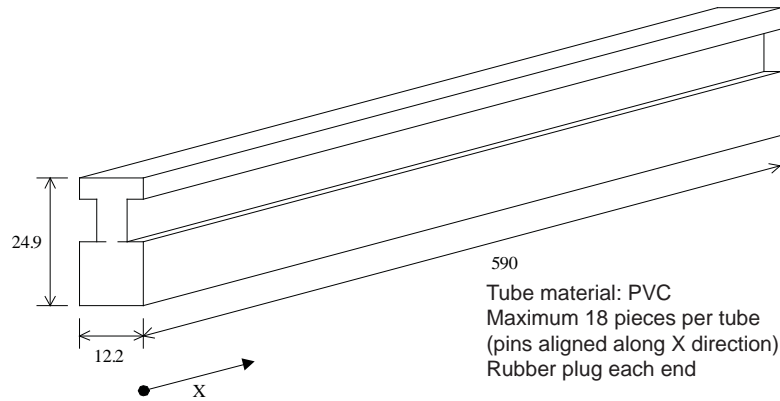
Maximum 15 tubes in Y direction
Maximum 4 tubes in Z direction

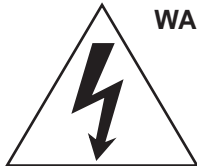
Maximum pieces per carton:
18 pieces per tube
15 tubes per layer
x 4 layers of tubes
1080 pieces per carton

Packing Specification

Leadforms 2452

Dimensions in millimeters





WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting this product on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce stress.
- Volatile-type silicone greases may permeate the product and produce cracks after long periods of time, resulting in reduced heat radiation effect, and possibly shortening the lifetime of the product.
- Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Type	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Momentive Performance Materials, Inc.
SC102	Dow Corning Toray Silicone Co., Ltd.

Heatsink Mounting Method

Torque When Tightening Mounting Screws. The recommended tightening torque for this product package type is: 58.8 to 78.4 N•cm (6.0 to 8.0 kgf•cm).

Soldering

- When soldering the products, please be sure to minimize the working time, within the following limits:
 - 260±5°C 10 s
 - 380±5°C 5 s
- Soldering iron should be at a distance of at least 1.5 mm from the body of the products

Electrostatic Discharge

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.

The products described herein are manufactured in Japan by Sanken Electric Co., Ltd. for sale by Allegro MicroSystems, Inc.

Sanken and Allegro reserve the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Therefore, the user is cautioned to verify that the information in this publication is current before placing any order.

When using the products described herein, the applicability and suitability of such products for the intended purpose shall be reviewed at the users responsibility.

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This datasheet is based on Sanken datasheet SSJ-03537



Worldwide ContactsAsia-Pacific**China****Sanken Electric Hong Kong Co., Ltd.**

Suite 1026, Ocean Centre
Canton Road, Tsimshatsui
Kowloon, Hong Kong
Tel: 852-2735-5262, Fax: 852-2735-5494

Sanken Electric (Shanghai) Co., Ltd.

Room 3202, Maxdo Centre
Xingyi Road 8, Changning District
Shanghai, China
Tel: 86-21-5208-1177, Fax: 86-21-5208-1757

Taiwan Sanken Electric Co., Ltd.

Room 1801, 18th Floor
88 Jung Shiau East Road, Sec. 2
Taipei 100, Taiwan R.O.C.
Tel: 886-2-2356-8161, Fax: 886-2-2356-8261

Japan**Sanken Electric Co., Ltd.
Overseas Sales Headquarters**

Metropolitan Plaza Building
1-11-1 Nishi-Ikebukuro, Toshima-ku
Tokyo 171-0021, Japan
Tel: 81-3-3986-6164, Fax: 81-3-3986-8637

Korea**Sanken Electric Korea Co., Ltd.**

Samsung Life Yeouido Building 16F
23-10, Yeouido-Dong, Yeongdeungpo-gu
Seoul 150-734, Korea
Tel: 82-2-714-3700, Fax: 82-2-3272-2145

Singapore**Sanken Electric Singapore Pte. Ltd.**

150 Beach Road, #14-03 The Gateway West
Singapore 189720
Tel: 65-6291-4755, Fax: 65-6297-1744

Europe**Sanken Power Systems (UK) Limited**

Pencoed Technology Park
Pencoed, Bridgend CF35 5HY, United Kingdom
Tel: 44-1656-869-100, Fax: 44-1656-869-162

North America**United States****Allegro MicroSystems, Inc.**

115 Northeast Cutoff
Worcester, Massachusetts 01606, U.S.A.
Tel: 1-508-853-5000, Fax: 1-508-853-7895

Allegro MicroSystems, Inc.

14 Hughes Street, Suite B105
Irvine, California 92618, U.S.A.
Tel: 1-949-460-2003, Fax: 1-949-460-7837